DISCRETE SEMICONDUCTORS

DATA SHEET

BTA216X series D, E and F Three quadrant triacs guaranteed commutation

Product specification

September 2018



Three quadrant triacs guaranteed commutation

BTA216X series D, E and F

GENERAL DESCRIPTION

Passivated guaranteed commutation triacs in a full pack, plastic envelope intended for use in motor control circuits or with other highly inductive loads. These devices balance the requirements of commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

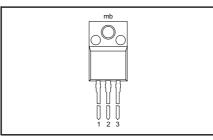
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{DRM}	BTA216X- BTA216X- BTA216X- Repetitive peak off-state voltages RMS on-state current	600D 600E 600F 600	V
I _{T(RMS)}	Non-repetitive peak on-state current	16 140	A A

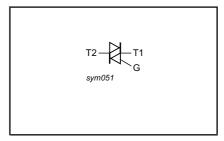
PINNING - SOT186A

PIN	DESCRIPTION			
1	main terminal 1			
2	main terminal 2			
3	gate			
case	isolated			

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DRM}	Repetitive peak off-state voltages		-	600¹	v
I _{T(RMS)}	RMS on-state current Non-repetitive peak	full sine wave; $T_{hs} \le 38 ^{\circ}C$ full sine wave;	-	16	A
l²t dl _⊤ /dt	on-state current I ² t for fusing Repetitive rate of rise of on-state current after	$\begin{split} & T_{\rm j} = 25~^{\circ}\text{C prior to} \\ & \text{surge} \\ & t = 20~\text{ms} \\ & t = 16.7~\text{ms} \\ & t = 10~\text{ms} \\ & l_{\text{TM}} = 20~\text{A;} \ l_{\rm G} = 0.2~\text{A;} \\ & dl_{\rm G}/\text{dt} = 0.2~\text{Å/}\mu\text{s} \end{split}$		140 150 98 100	Α Α Α²s Α/μs
$\begin{matrix} I_{GM} \\ P_{GM} \\ P_{G(AV)} \end{matrix}$	triggering Peak gate current Peak gate power Average gate power Storage temperature Operating junction temperature	over any 20 ms period	- - -40 -	2 5 0.5 150 125	A W C C

September 2018 1 Rev 2.100

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/ μ s.

WeEn Semiconductors Product specification

Three quadrant triacs guaranteed commutation

BTA216X series D, E and F

ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	-	1	2500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-hs}	Thermal resistance junction to heatsink	full or half cycle with heatsink compound without heatsink compound	1 1		4.0 5.5	K/W K/W
R _{th j-a}	Thermal resistance junction to ambient	in free air	-	55	-	K/W

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
		BTA216X-		D	Е	F	
I _{GT}	Gate trigger current ²	$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$					_
		T2+ G+ T2+ G-	-	5	10 10	25 25	mA mA
		T2- G-	_	5 5 5	10	25 25	mA
IL	Latching current	$V_{D} = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$		45	0.5	00	
		T2+ G+ T2+ G-	-	15 25	25 30	30 40	mA mA
		T2- G-	-	25	30	40	mA
I _H	Holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$	-	15	25	30	mA
					D, E, F	1	
V_T	On-state voltage	I _T = 20 A	-		1.5		V
V _{GT}	Gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$	- 0.25		1.5		V
		$V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; I_T = 125 \text{ °C}$	0.25		-		V
I_D	Off-state leakage current	$V_D = V_{DRM(max)}$; $T_j = 125 ^{\circ}C$	-		0.5		mA

September 2018 2 Rev 2.100

² Device does not trigger in the T2-, G+ quadrant.

WeEn Semiconductors Product specification

Three quadrant triacs guaranteed commutation

BTA216X series D, E and F

DYNAMIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.		MAX.	UNIT
		BTA216X-	D	Е	F		
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)};$ $T_j = 110 ^{\circ}C;$ exponential waveform; gate open	30	60	70	-	V/μs
dl _{com} /dt	Critical rate of change of commutating current	circuit $V_{DM} = 400 \text{ V}; T_j = 125 ^{\circ}\text{C};$ $I_{T(RMS)} = 16 \text{ A};$ $dV_{com}/dt = 10 \text{V}/\mu\text{s};$ gate open circuit	2.5	6.2	18	-	A/ms
dI _{com} /dt	Critical rate of change of commutating current	$\begin{array}{l} \text{Open circuit} \\ \text{V}_{\text{DM}} = 400 \text{ V; T}_{j} = 125 \text{ °C;} \\ \text{I}_{\text{T(RMS)}} = 16 \text{ A;} \\ \text{dV}_{\text{com}}/\text{dt} = 0.1 \text{V/}\mu\text{s; gate} \\ \text{open circuit} \end{array}$	12	20	50	1	A/ms

WeEn Semiconductors Product specification

Three quadrant triacs guaranteed commutation

BTA216X series D, E and F

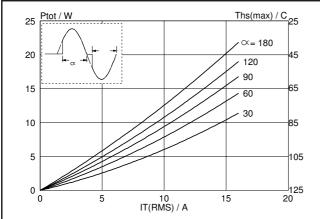


Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where α = conduction angle.

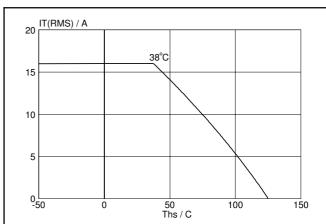


Fig.4. Maximum permissible rms current $I_{T(RMS)}$, versus heatsink temperature T_{hs} .

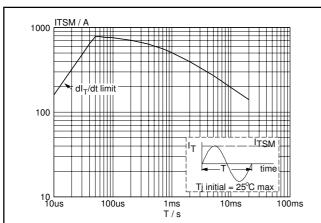


Fig.2. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \le 20$ ms.

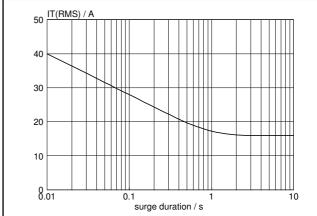


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{hs} \le 38 \,^{\circ}\text{C}$.

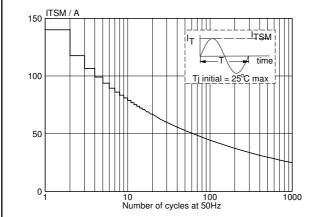


Fig.3. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, f = 50 Hz.

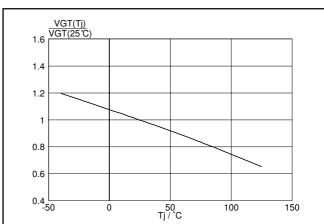
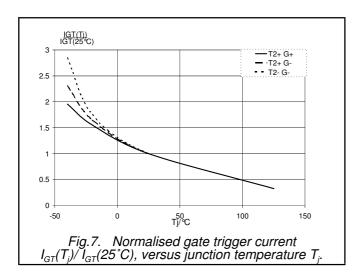


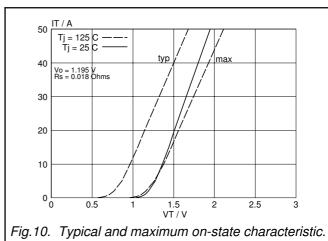
Fig.6. Normalised gate trigger voltage $V_{GT}(T_j)/V_{GT}(25^{\circ}C)$, versus junction temperature T_{j} .

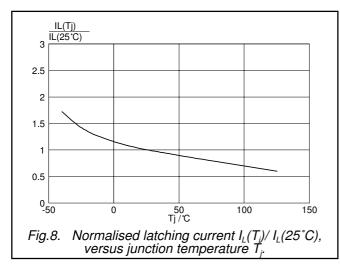
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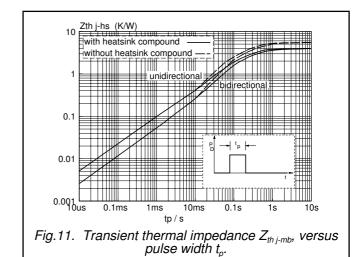
Three quadrant triacs guaranteed commutation

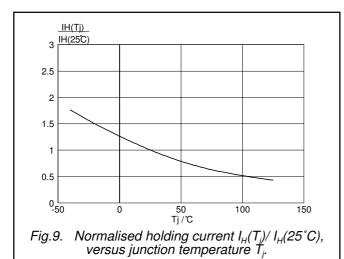
BTA216X series D, E and F











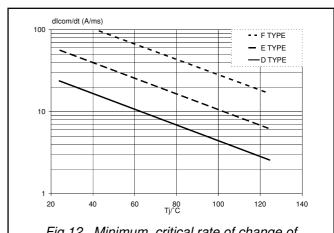
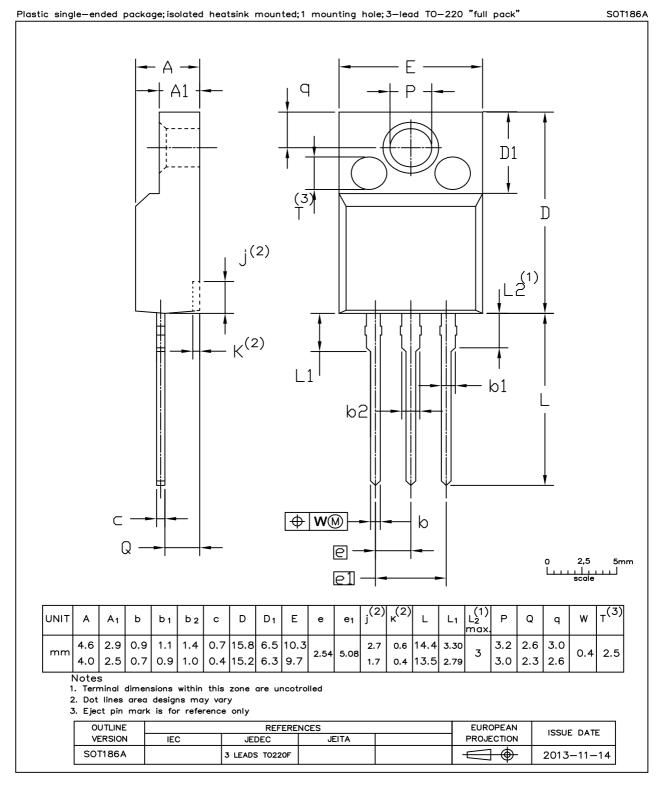


Fig.12. Minimum, critical rate of change of commutating current dI_{com}/dt versus junction temperature, $dV_{com}/dt = 10V/\mu s$.

Three quadrant triacs guaranteed commutation

BTA216X series D, E and F

MECHANICAL DATA



Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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